

CSD18502KCS 40V N 沟道 NexFET™ 功率 MOSFET

1 特性

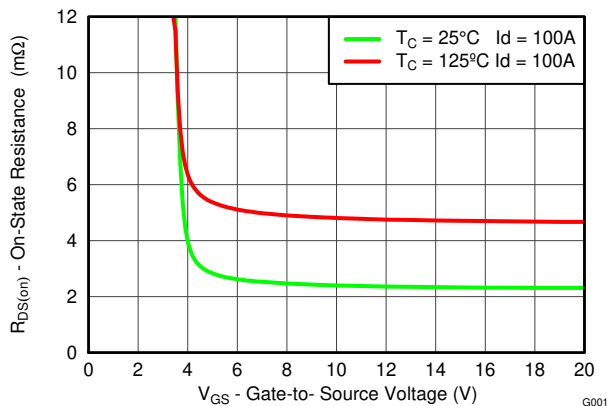
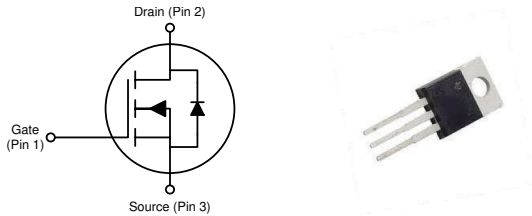
- 超低 Q_g 和 Q_{gd}
- 低热阻
- 雪崩级
- 逻辑电平
- 无铅引脚镀层
- 符合 RoHS
- 无卤素
- TO-220 塑料封装

2 应用

- 直流/直流转换
- 次级侧同步整流器
- 电机控制

3 说明

这款 40V、2.4mΩ、TO-220 NexFET™ 功率 MOSFET 旨在用于更大幅度地降低功率转换应用中的损耗。



$R_{DS(on)}$ 与 V_{GS} 之间的关系

产品概要

$T_A = 25^\circ\text{C}$		典型值	单位
V_{DS}	漏源电压	40	V
Q_g	栅极电荷总量 (10V)	52	nC
Q_{gd}	栅极电荷 (栅极到漏极)	8.4	nC
$R_{DS(on)}$	漏源导通电阻	$V_{GS} = 4.5\text{V}$	3.3 mΩ
		$V_{GS} = 10\text{V}$	2.4 mΩ
$V_{GS(th)}$	阈值电压	1.8	V

订购信息⁽¹⁾

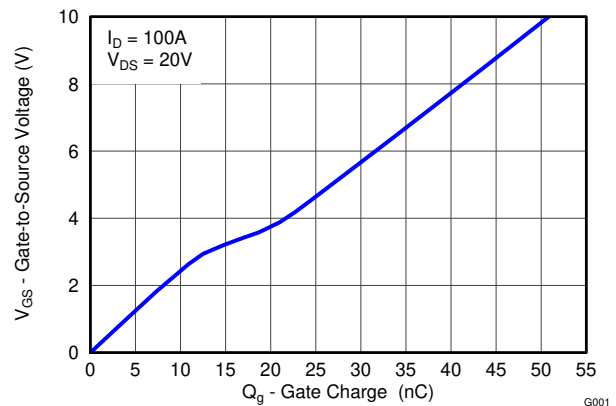
器件	封装	介质	数量	出货
CSD18502KCS	TO-220 塑料封装	管	50	管

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

绝对最大额定值

$T_A = 25^\circ\text{C}$		值	单位
V_{DS}	漏源电压	40	V
V_{GS}	栅源电压	± 20	V
I_D	持续漏极电流 (受封装限制)	100	A
	持续漏极电流 (受芯片限制), $T_C = 25^\circ\text{C}$ 时测得	212	
	持续漏极电流 (受芯片限制), $T_C = 100^\circ\text{C}$ 时测得	150	
I_{DM}	脉冲漏极电流 ⁽¹⁾	400	A
P_D	功率耗散	259	W
T_J , T_{stg}	工作结温和贮存温度范围	-55 至 175	$^\circ\text{C}$
E_{AS}	Avalanche Energy, 单脉冲 $I_D = 81\text{A}$, $L = 0.1\text{mH}$, $R_G = 25\Omega$	330	mJ

(1) 最大 $R_{\theta JC} = 0.6^\circ\text{C/W}$, 脉冲持续时间 $\leq 100\mu\text{s}$, 占空比 $\leq 1\%$



栅极电荷



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4 Specifications

4.1 Electrical Characteristics

(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
STATIC CHARACTERISTICS							
BV _{DSS}	Drain-to-Source Voltage	V _{GS} = 0V, I _D = 250μA	40			V	
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0V, V _{DS} = 32V	1			μA	
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0V, V _{GS} = 20V	100			nA	
V _{GS(th)}	Gate-to-Source Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	1.5	1.8	2.1	V	
R _{DS(on)}	Drain-to-Source On Resistance	V _{GS} = 4.5V, I _D = 100A	3.3			4.3	mΩ
		V _{GS} = 10V, I _D = 100A	2.4			2.9	mΩ
g _{fs}	Transconductance	V _{DS} = 20V, I _D = 100A	138			S	
DYNAMIC CHARACTERISTICS							
C _{iss}	Input Capacitance	V _{GS} = 0V, V _{DS} = 20V, f = 1MHz	3900			4680	pF
C _{oss}	Output Capacitance		900			1080	pF
C _{rss}	Reverse Transfer Capacitance		21			26	pF
R _G	Series Gate Resistance		1.2			2.4	Ω
Q _g	Gate Charge Total (4.5 V)	V _{DS} = 20V, I _D = 100A	25			30	nC
Q _g	Gate Charge Total (10 V)		52			62	nC
Q _{gd}	Gate Charge Gate-to-Drain		8.4				nC
Q _{gs}	Gate Charge Gate-to-Source		10.3				nC
Q _{g(th)}	Gate Charge at V _{th}		7.5				nC
Q _{oss}	Output Charge	V _{DS} = 20V, V _{GS} = 0V	52				nC
t _{d(on)}	Turn On Delay Time	V _{DS} = 20V, V _{GS} = 10V, I _{DS} = 100A, R _G = 0Ω	11				ns
t _r	Rise Time		7.3				ns
t _{d(off)}	Turn Off Delay Time		33				ns
t _f	Fall Time		9.3				ns
DIODE CHARACTERISTICS							
V _{SD}	Diode Forward Voltage	I _{SD} = 100A, V _{GS} = 0V	0.8			1	V
Q _{rr}	Reverse Recovery Charge	V _{DS} = 20V, I _F = 100A,	105				nC
t _{rr}	Reverse Recovery Time	di/dt = 300A/μs	48				ns

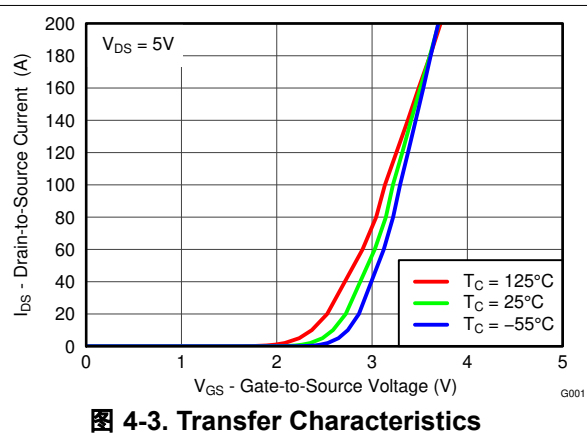
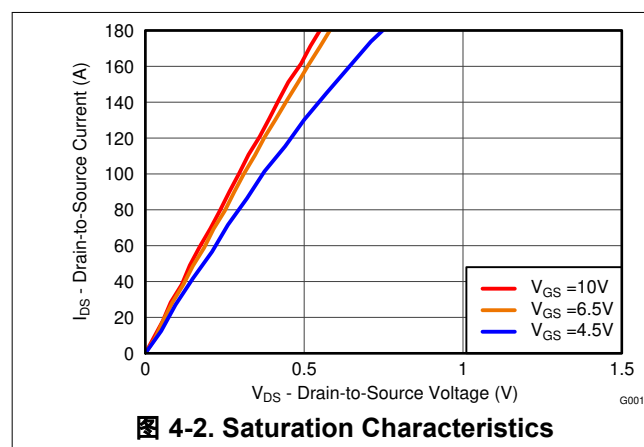
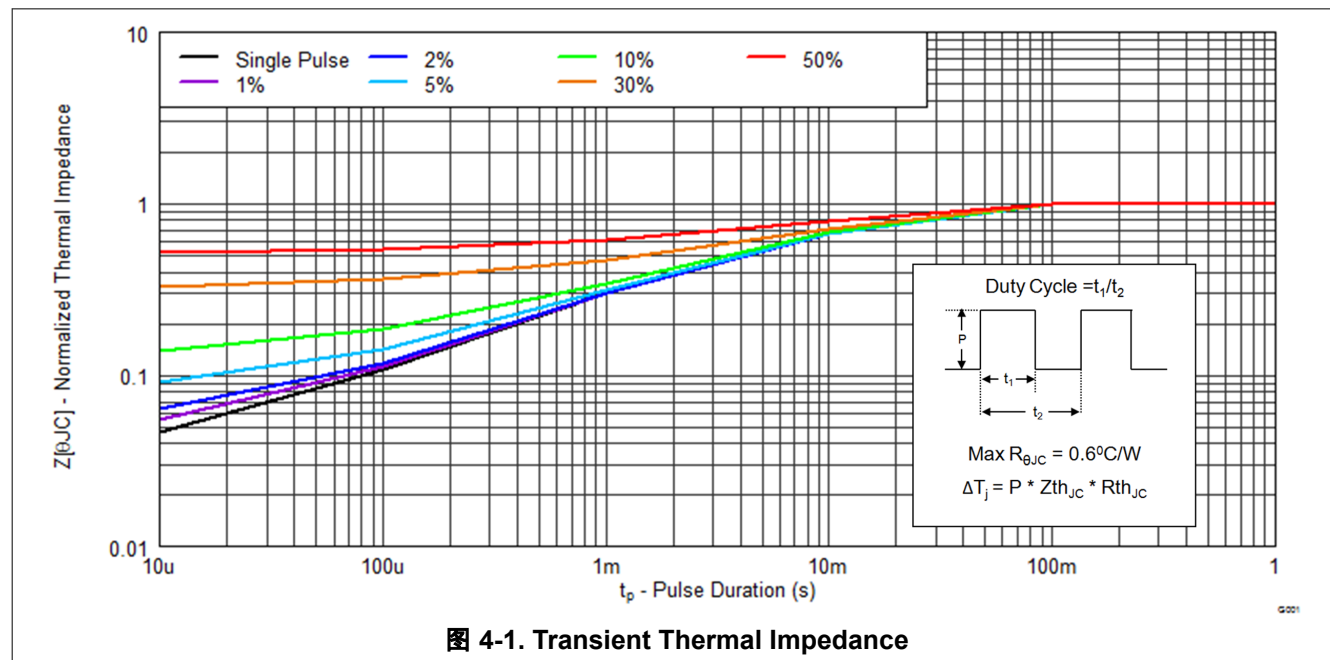
4.2 Thermal Information

(T_A = 25°C unless otherwise stated)

THERMAL METRIC		MIN	TYP	MAX	UNIT
R _{θJC}	Junction-to-Case Thermal Resistance			0.6	°C/W
R _{θJA}	Junction-to-Ambient Thermal Resistance			62	

4.3 Typical MOSFET Characteristics

($T_A = 25^\circ\text{C}$ unless otherwise stated)



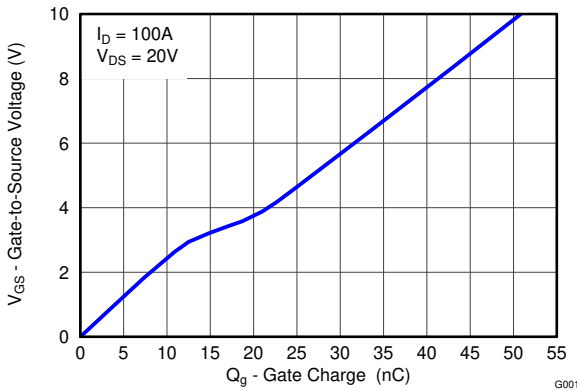


图 4-4. Gate Charge

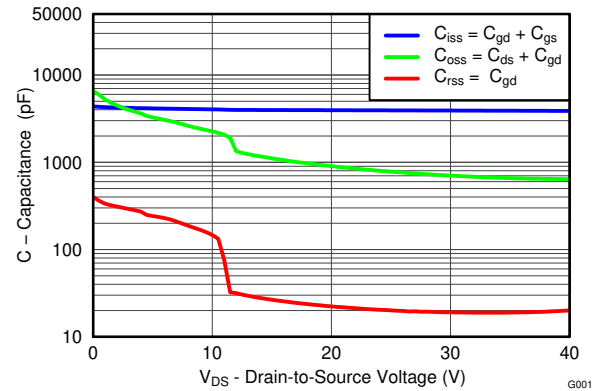


图 4-5. Capacitance

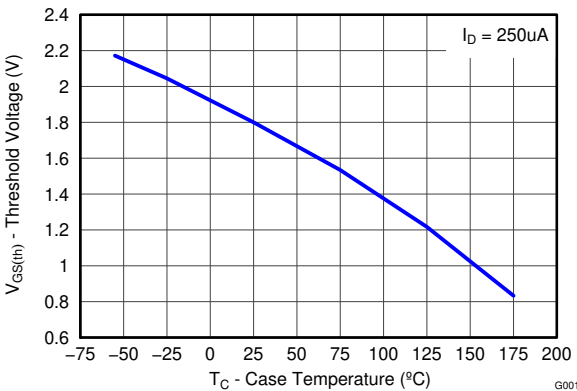


图 4-6. Threshold Voltage vs. Temperature

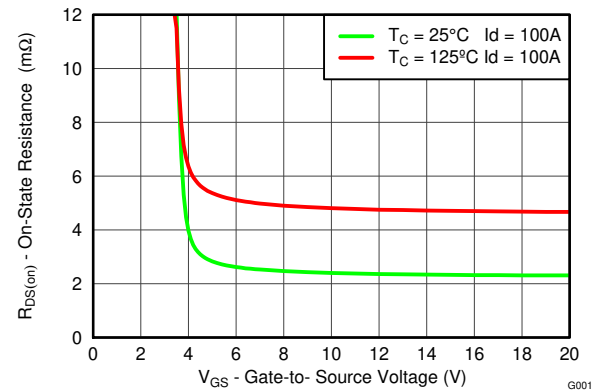


图 4-7. On-State Resistance vs. Gate-to-Source Voltage

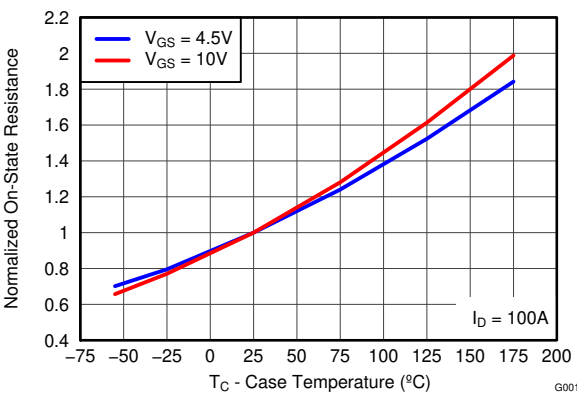


图 4-8. Normalized On-State Resistance vs. Temperature

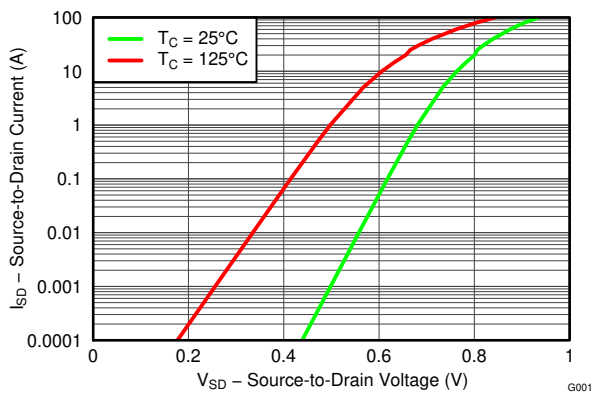


图 4-9. Typical Diode Forward Voltage

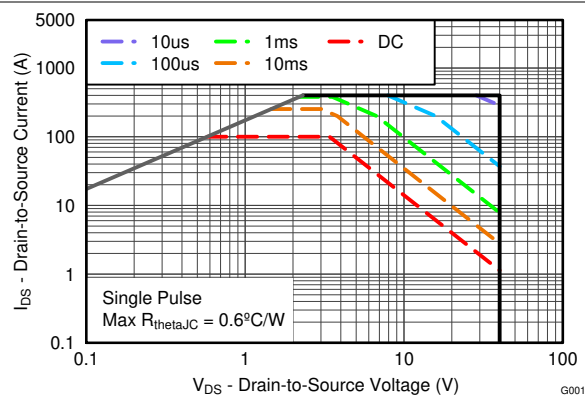


图 4-10. Maximum Safe Operating Area

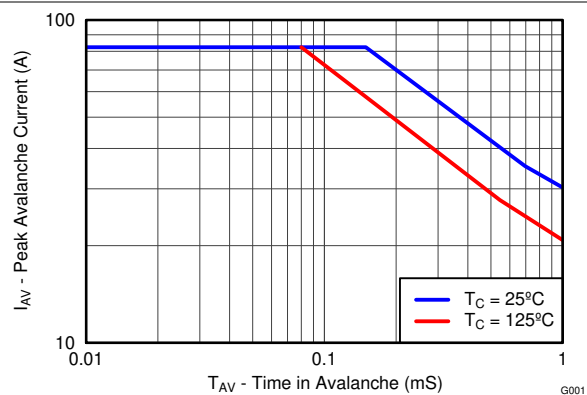


图 4-11. Single Pulse Unclamped Inductive Switching

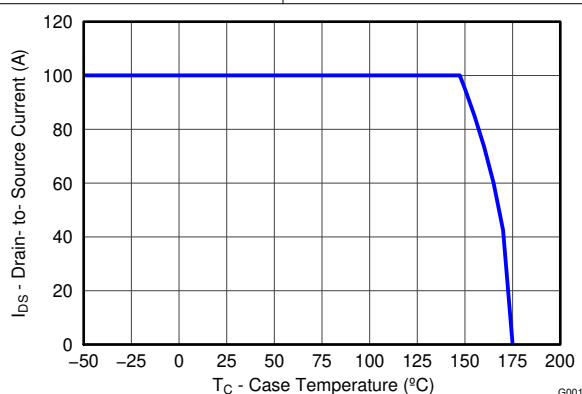


图 4-12. Maximum Drain Current vs. Temperature

5 Device and Documentation Support

5.1 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [通知](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

5.2 支持资源

[TI E2E™ 中文支持论坛](#) 是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [使用条款](#)。

5.3 Trademarks

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ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

5.5 术语表

TI 术语表

本术语表列出并解释了术语、首字母缩略词和定义。

6 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision B (July 2014) to Revision C (March 2024) Page

- 更新了整个文档中的表格、图和交叉参考的编号格式..... 1

Changes from Revision A (October 2012) to Revision B (July 2014) Page

- $T_C = 25^\circ$ 时的连续漏极电流增加至 212A..... 1
- $T_C = 125^\circ$ 时的连续漏极电流增加至 150A..... 1
- 脉冲漏极电流增加至 400A..... 1
- 最大功耗增加至 259W..... 1
- 最大工作结温和存储温度增加至 175° 1
- 更新了脉冲电流条件..... 1
- Updated 图 4-1 from a normalized $R_{\theta JA}$ to an $R_{\theta JC}$ curve..... 4
- Updated 图 4-6 to extend to 175°C 4
- Updated 图 4-8 to extend to 175°C 4
- Updated the SOA in 图 4-10 4
- Updated 图 4-12 to extend to 175°C 4

Changes from Revision * (August 2012) to Revision A (October 2012) Page

- Changed the Transconductance TYP value From: 149S To: 138S..... 3
- Changed $R_{\theta JA}$ From: 65°C/W To: 62°C/W 3

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CSD18502KCS	Active	Production	TO-220 (KCS) 3	50 TUBE	ROHS Exempt	SN	N/A for Pkg Type	-55 to 175	CSD18502KCS
CSD18502KCS.B	Active	Production	TO-220 (KCS) 3	50 TUBE	ROHS Exempt	SN	N/A for Pkg Type	-55 to 175	CSD18502KCS

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

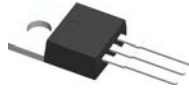
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
CSD18502KCS	KCS	TO-220	3	50	532	34.1	700	9.6
CSD18502KCS.B	KCS	TO-220	3	50	532	34.1	700	9.6

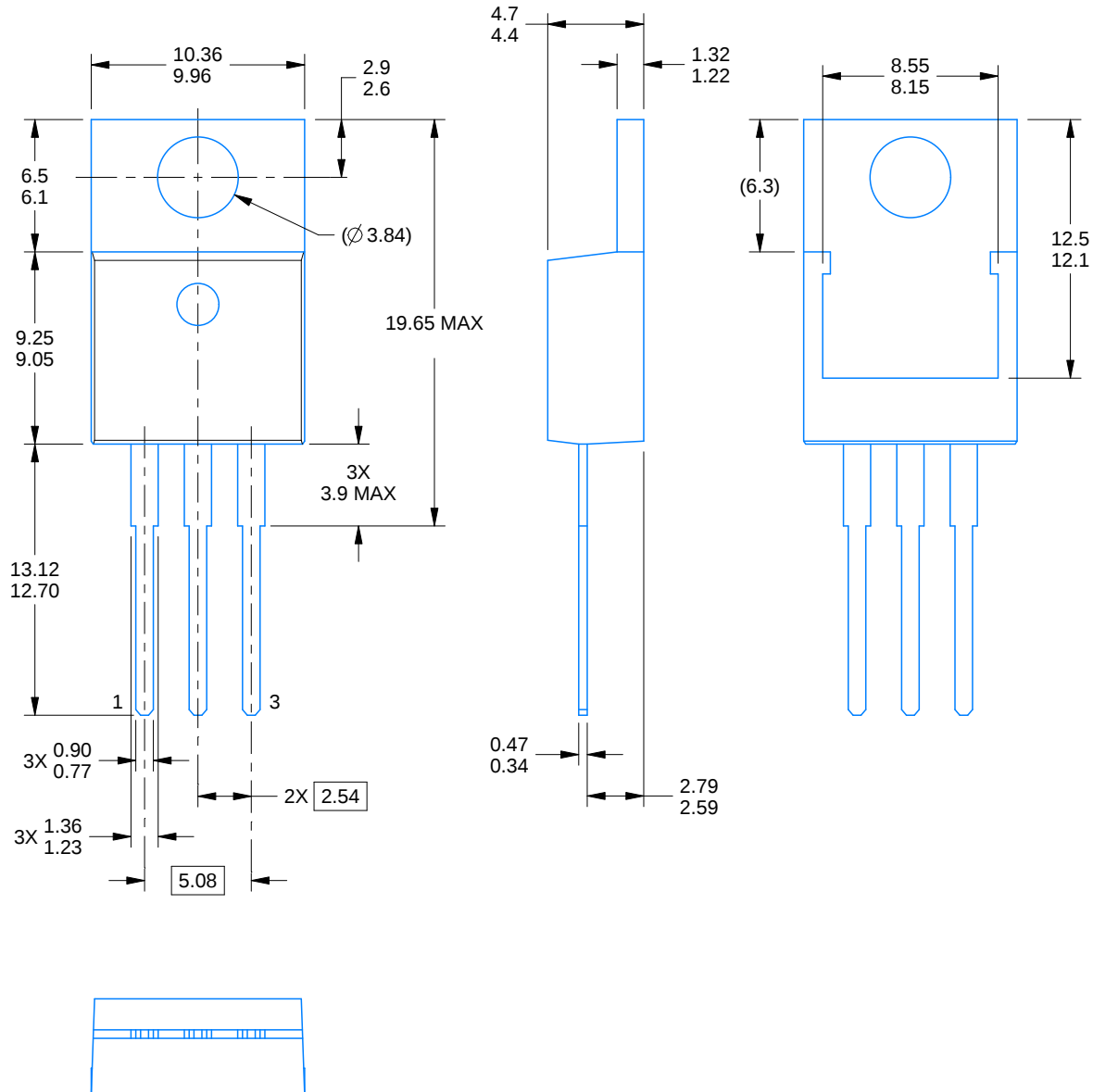


PACKAGE OUTLINE

KCS0003B

TO-220 - 19.65 mm max height

TO-220



4222214/B 08/2018

NOTES:

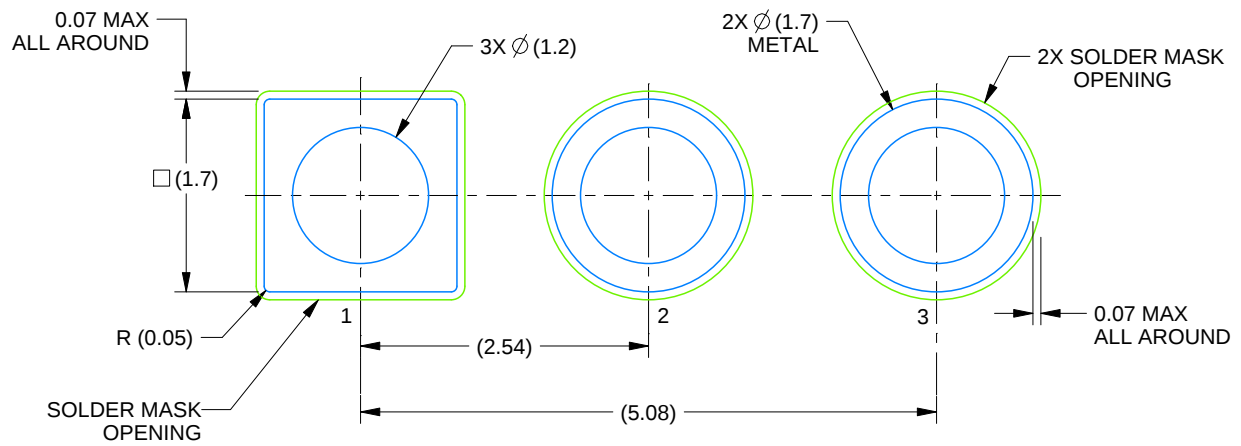
1. Dimensions are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-220.

EXAMPLE BOARD LAYOUT

KCS0003B

TO-220 - 19.65 mm max height

TO-220



LAND PATTERN EXAMPLE
NON-SOLDER MASK DEFINED
SCALE:15X

4222214/B 08/2018

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最后更新日期：2025 年 10 月